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With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

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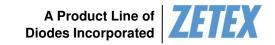












50V DUAL NPN LOW SATURATION SWITCHING TRANSISTOR IN SOT26

Features

- $BV_{CEO} > 50V$
- I_C = 1A High Continuous Current
- High Gain
- $R_{SAT} = 160 m\Omega$ for Low Equivalent On Resistance
- Low Saturation Voltage V_{CE(sat)} < -270mV @ 1A
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

Mechanical Data

- Case: SOT26
- Case Material: Molded Plastic, "Green" Molding Compound; UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads; Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.015 grams (Approximate)

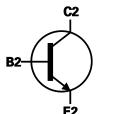
Applications

C1

- LCD Backlighting Inverter Circuits
- Boost Functions in DC-DC Converters

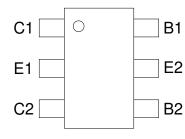






Device Symbol

B1



Top View Pin-Out

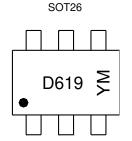
Ordering Information (Notes 4 & 5)

Product	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZXTD09N50DE6TA	AEC-Q101	D619	7	8	3,000
ZTD09N50DE6QTA	Automotive	D619	7	8	3,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and
- <1000ppm antimony compounds.
 4. Automotive products are AEC-Q101 qualified and PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified.
- 5. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



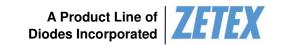
D619 = Product Type Marking Code YM = Date Code Marking Y or \overline{Y} = Year (ex: C = 2015)

M or \overline{M} = Month (ex: 9 = September)

Date Code Key

Year	201	5	2016	2017	2018	2019	2020	202	1 20	22	2023	2024	2025
Code	С		D	E	F	G	Н	I	,	J	K	L	М
Montl	h	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	:	1	2	3	4	5	6	7	8	9	0	N	D





Absolute Maximum Ratings - Q1 & Q2 Common (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	50	V
Collector-Emitter Voltage	$V_{\sf CEO}$	50	٧
Emitter-Base Voltage	V_{EBO}	7	V
Continuous Collector Current	Ic	1	Α
Peak Pulse Current	Ісм	2	Α
Base Current	Ι _Β	200	mA

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit	
	(Notes 6 & 10)		0.7 5.6		
	(Notes 7 & 10)	P _D	0.9 7.2		
Power Dissipation Linear Derating Factor	(Notes 7 & 11)		1.1 8.8	W mW/°C	
	(Notes 8 & 10)		1.1 8.8		
	(Notes 9 & 10)		1.7 13.6		
	(Notes 6 & 10)		179		
	(Notes 7 & 10)	$R_{ hetaJA}$	139		
Thermal Resistance, Junction to Ambient	(Notes 7 & 11)		113	000	
	(Notes 8 & 10)		113	°C/W	
	(Notes 9 & 10)		73		
Thermal Resistance, Junction to Lead	(Note 12)	$R_{ hetaJL}$	95.50		
Operating and Storage Temperature Range		T _J , T _{STG}	-55 to +150	°C	

ESD Ratings (Note 13)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

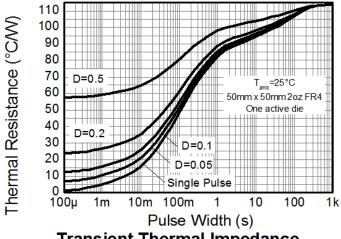
Notes:

- 6. For a device surface mounted on 15mm x 15mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions; the device is measured when operating in a steady-state condition.
- 7. Same as Note 6, except the device is surface mounted on 25mm x 25mm 1oz copper.
- 8. Same as Note 6, except the device is surface mounted on $50 \text{mm} \times 50 \text{mm}$ 2oz copper.
- 9. Same as Note 8, except the device is measured at t < 5 seconds.
- 10. For device with one active die, both collectors attached to a common heatsink.
- 11. For device with two active dice running at equal power, split heatsink 50% to each collector.
- 12. Thermal resistance from junction to solder-point (at the end of the collector lead).

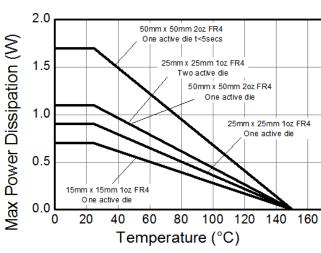
 13. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



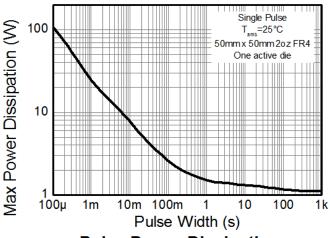
Thermal Characteristics and Derating Information



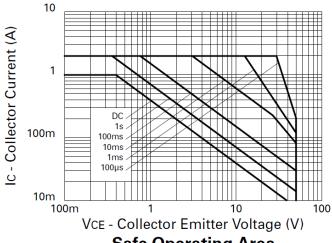
Transient Thermal Impedance



Derating Curve



Pulse Power Dissipation



Safe Operating Area





Electrical Characteristics - Q1 & Q2 common (@T_A = +25°C, unless otherwise specified.)

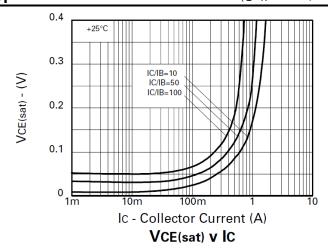
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV_{CBO}	50	_	_	V	$I_C = 100\mu A$
Collector-Emitter Breakdown Voltage (Note 13)	BV _{CEO}	50	_	_	V	$I_C = 10mA$
Emitter-Base Breakdown Voltage	BV_{EBO}	7	_	_	٧	$I_E = 100\mu A$
Collector-Base Cut-Off Current	I _{CBO}	_		10	nA	$V_{CB} = 40V$
Collector-Emitter Cut-Off Current	I _{CES}		_	10	nA	V _{CES} = 40V
Emitter Cutoff Current	I _{EBO}		_	10	nA	$V_{EB} = 5.6V$
DC Current Gain (Note 13)	h _{FE}	200 300 200 75 20	420 450 350 130 60		l	$\begin{split} &I_{C} = 10\text{mA}, \ V_{CE} = 2\text{V} \\ &I_{C} = 100\text{mA}, \ V_{CE} = 2\text{V} \\ &I_{C} = 500\text{mA}, \ V_{CE} = 2\text{V} \\ &I_{C} = 1\text{A}, \ V_{CE} = 2\text{V} \\ &I_{C} = 1.5\text{A}, \ V_{CE} = 2\text{V} \end{split}$
Collector-Emitter Saturation Voltage (Note 13)	V _{CE(sat)}	_	24 60 120 160	35 80 200 270	mV	$I_C = 100$ mA, $I_B = 10$ mA $I_C = 250$ mA, $I_B = 10$ mA $I_C = 500$ mA, $I_B = 10$ mA $I_C = 1$ A, $I_B = 50$ mA
Base-Emitter Saturation Voltage (Note 13)	$V_{BE(sat)}$		940	1100	mV	$I_C = 1A$, $I_B = 50mA$
Base-Emitter Turn-On Voltage (Note 13)	$V_{BE(on)}$		850	1100	mV	$I_C = 1A$, $V_{CE} = 2V$
Output Capacitance	C_{obo}		10	_	рF	V _{CB} = 10V. f = 1MHz
Current Gain-Bandwidth Product	f _T	_	215	_	MHz	$V_{CE} = 10V, I_{C} = 50mA$ f = 100MHz
Turn-On Time	t _{on}	_	150	_	ns	$V_{CC} = 10V, I_{C} = 1A$
Turn-Off Time	t _{off}	_	425	_	ns	$I_{B1} = I_{B2} = 100 \text{mA}$

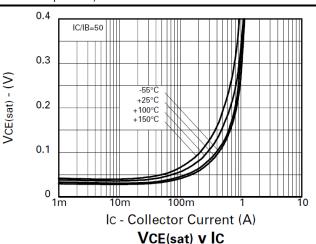
Note:

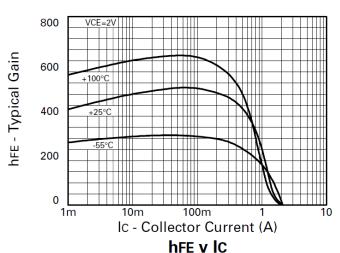
13. Measured under pulsed conditions. Pulse width ≤ 300 µs. Duty cycle ≤ 2%.

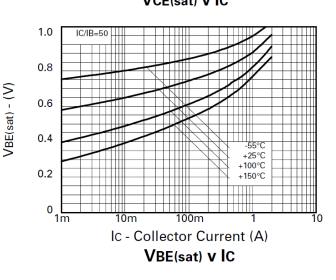


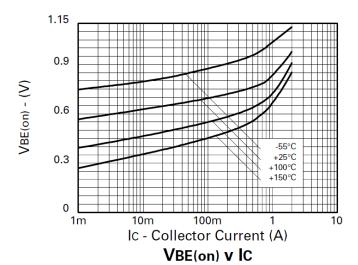
Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)



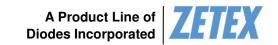






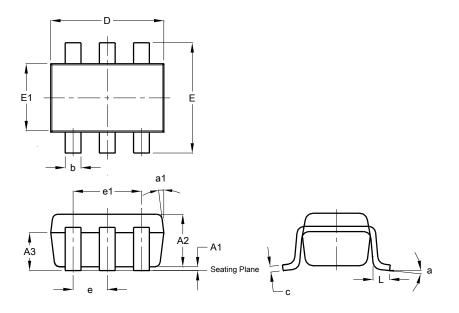






Package Outline Dimensions

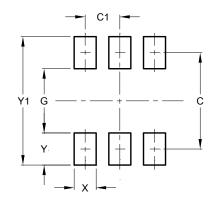
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



SOT26						
Dim	Min	Max	Тур			
A1	0.013	0.10	0.05			
A2	1.00	1.30	1.10			
A3	0.70	0.80	0.75			
b	0.35	0.50	0.38			
С	0.10	0.20	0.15			
D	2.90	3.10	3.00			
е	1	1	0.95			
e1	-	1	1.90			
Е	2.70	3.00	2.80			
E1	1.50	1.70	1.60			
L	0.35	0.55	0.40			
а	-	-	8°			
a1	-	-	7°			
All Dimensions in mm						

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
С	2.40
C1	0.95
G	1.60
X	0.55
Υ	0.80
Y1	3.20





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